

P-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- Surface-mounted package
- Advanced trench cell design

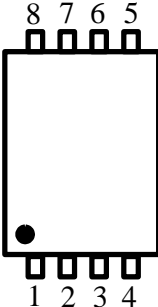
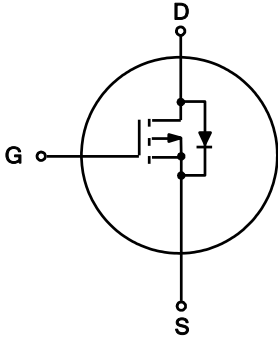
1.2 Applications

- LCD TV appliances
- High power inverter system
- LCDM appliances

1.3 Quick reference

- $BV \geq -100\text{ V}$
- $R_{DS(ON)} \leq 65\text{m}\Omega @ V_{GS} = -10\text{ V}$
- $P_{tot} \leq 50\text{ W}$
- $R_{DS(ON)} \leq 73\text{m}\Omega @ V_{GS} = -4.5\text{ V}$
- $I_D \leq -30\text{ A}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1,2,3	Source	 <p>Top View PDFN5x6-8L</p>	
4	Gate		
5,6,7,8	Drain		



3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	Drain-Source Voltage	T _C = 25 °C	- 100	-	V
V _{GS}	Gate-Source Voltage	T _C = 25 °C	-	±20	V
I _D *	Drain Current (DC)	T _C = 25 °C, V _{GS} = - 10 V	-	- 30	A
		T _C = 100 °C, V _{GS} = - 10 V		- 18	A
I _{DM} **	Drain Current (Pulsed)	T _C = 25 °C, V _{GS} = - 10 V	-	- 76	A
P _{tot}	Drain power dissipation	T _C = 25 °C	-	50	W
T _{stg}	Storage Temperature		-55	150	°C
T _J	Junction Temperature		-	150	°C
I _S	Continuous-Source Current	T _C = 25 °C	-	- 30	A
E _{AS} *	Single Pulsed Avalanche Energy	V _{DD} = - 50 V , L= 1.0 mH	-	242	mJ
R _{θJA} *	Thermal Resistance- Junction to Ambient		-	50	°C/W
R _{θJC} *	Thermal Resistance- Junction to Case		-	2.5	

Notes :

- * Surface Mounted on 1 in² pad area, t ≤ 10 sec
- ** Pulse width ≤ 300 μs, duty cycle ≤ 2 %
- *** Limited by bonding wire

4. Marking Information

Product Name	Marking
KJ30P10G	30P10 YWWXXX YWWXXX: Date Code

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
KJ30P10G	PDFN5X6-8L			5000	

Note: KUAJIJIXIN defines " Green " as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC / JEDEC J-STD-020C)

6. Electrical Characteristics ($T_A = 25\text{ }^\circ\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}$, $I_{DS} = -250\text{ }\mu\text{A}$	-100	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_{DS} = -250\text{ }\mu\text{A}$	-1	-	-2	V
I_{DSS}	Drain Leakage Current	$V_{DS} = -50\text{ V}$, $V_{GS} = 0\text{ V}$	-	-	-1	μA
		$T_J = 85\text{ }^\circ\text{C}$	-	-	-30	μA
I_{GSS}	Gate Leakage Current	$V_{GS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$	-	-	± 100	nA
$R_{DS(on)}^a$	On-State Resistance	$V_{GS} = -10\text{ V}$, $I_{DS} = -10\text{ A}$	-	57	65	m Ω
		$V_{GS} = -4.5\text{ V}$, $I_{DS} = -5\text{ A}$	-	63	73	
Diode Characteristics						
V_{SD}^a	Diode Forward Voltage	$I_{SD} = -10\text{ A}$, $V_{GS} = 0\text{ V}$	-	-	-1.2	V
t_{rr}	Reverse Recovery Time	$I_{DS} = -10\text{ A}$, $di_{SD}/dt = 100\text{ A}/\mu\text{s}$	-	32	-	ns
Q_{rr}	Reverse Recovery Charge		-	49	-	nC
Dynamic Characteristics^b						
C_{iss}	Input Capacitance	$V_{GS} = 0\text{ V}$, $V_{DS} = -50\text{ V}$ Frequency = 1 MHz	-	4507	-	pF
C_{oss}	Output Capacitance		-	97	-	
C_{riss}	Reverse Transfer Capacitance		-	15	-	
$t_d(on)$	Turn-on Delay Time	$V_{DS} = -50\text{ V}$, $V_{GEN} = -10\text{ V}$, $R_G = 4.5\text{ }\Omega$, $R_L = 5\text{ }\Omega$, $I_{DS} = -10\text{ A}$	-	49	-	ns
t_r	Turn-on Rise Time		-	71	-	
$t_d(off)$	Turn-off Delay Time		-	555	-	
t_f	Turn-off Fall Time		-	187	-	
Gate Charge Characteristics^b						
Q_g	Total Gate Charge	$V_{DS} = -50\text{ V}$, $V_{GS} = -10\text{ V}$, $I_{DS} = -10\text{ A}$	-	73	-	nC
Q_{gs}	Gate-Source Charge		-	17	-	
Q_{gd}	Gate-Drain Charge		-	9.1	-	

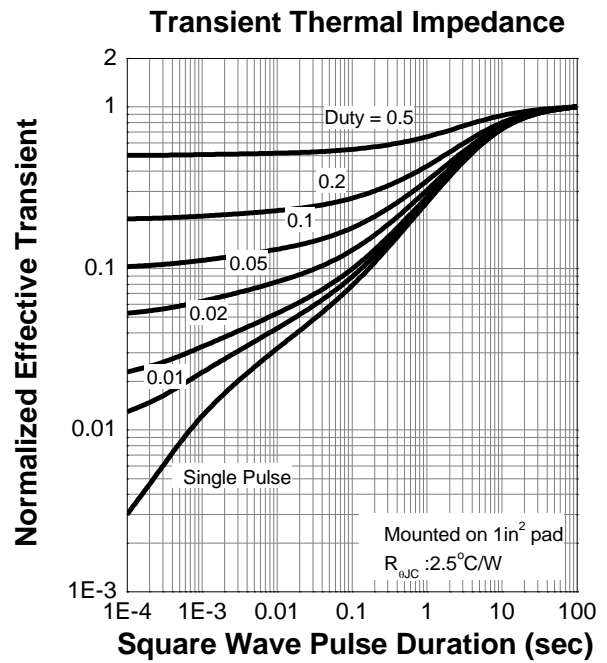
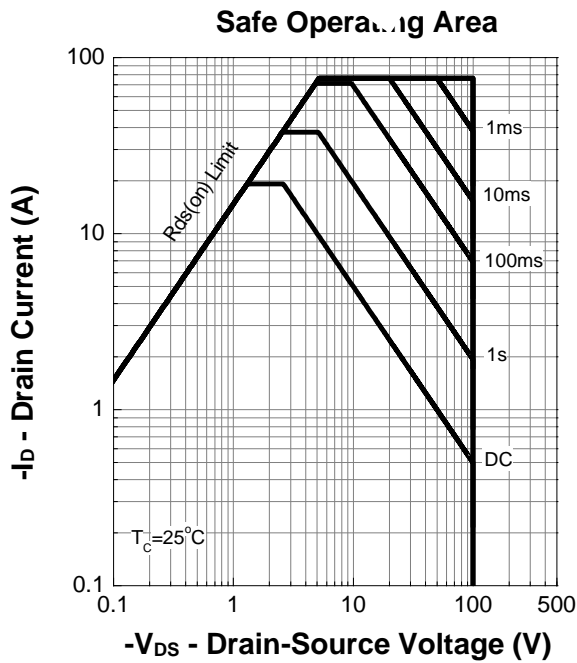
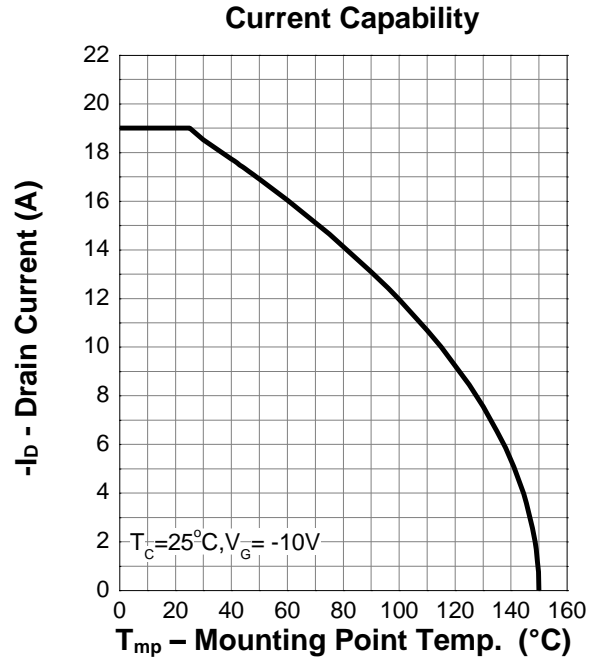
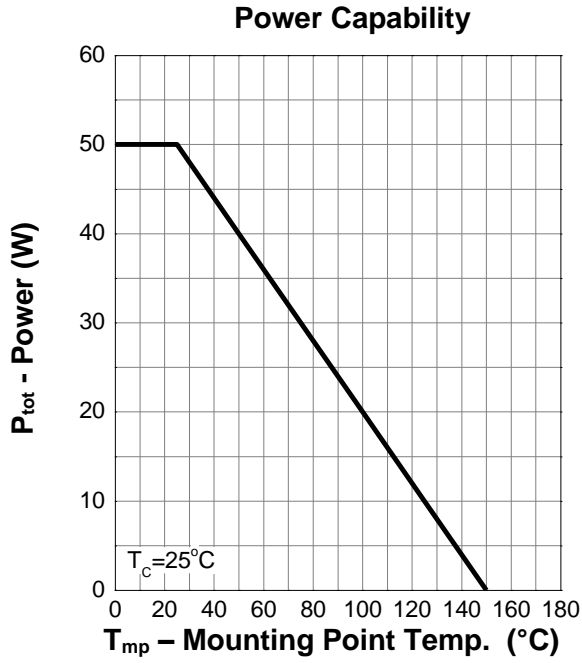
Notes :

a : Pulse test ; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

b : Guaranteed by design, not subject to production testing

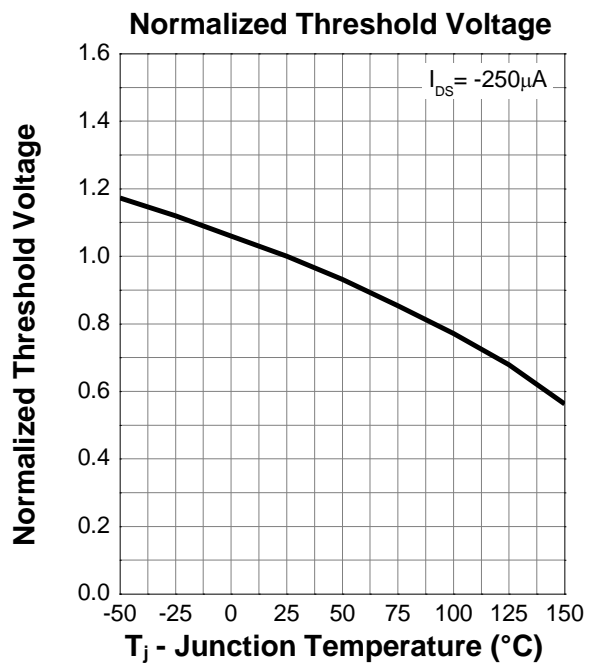
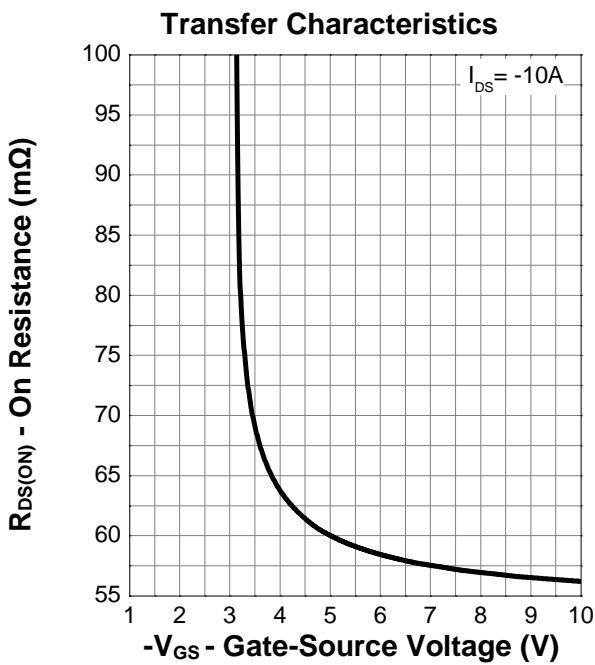
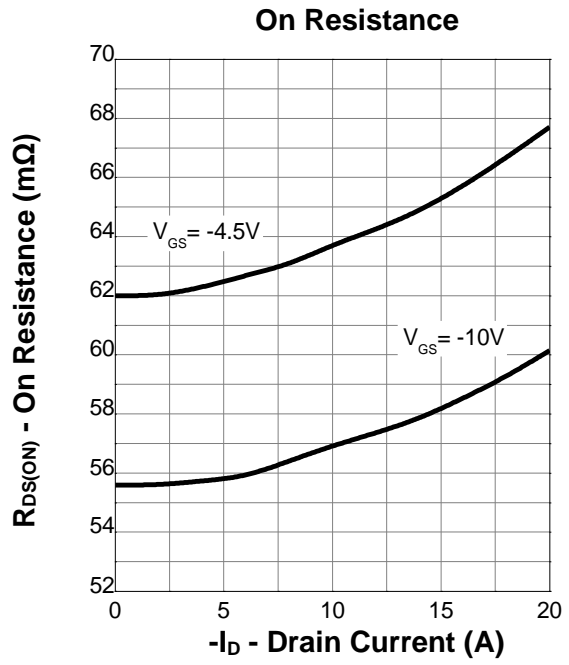
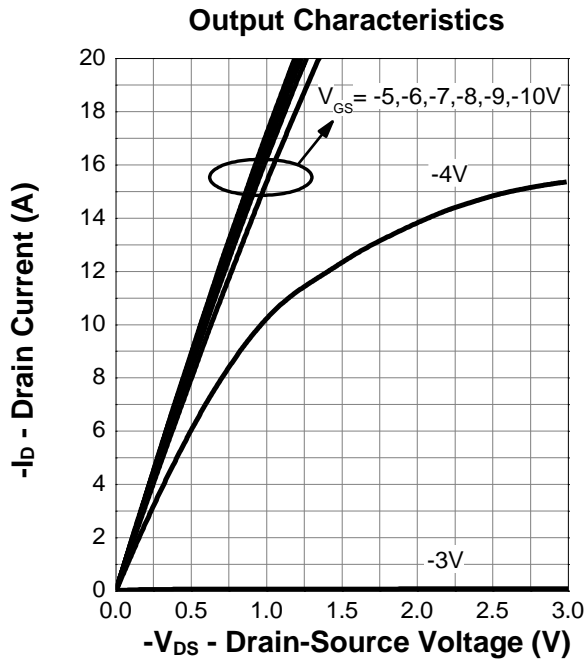


7. Typical Characteristics



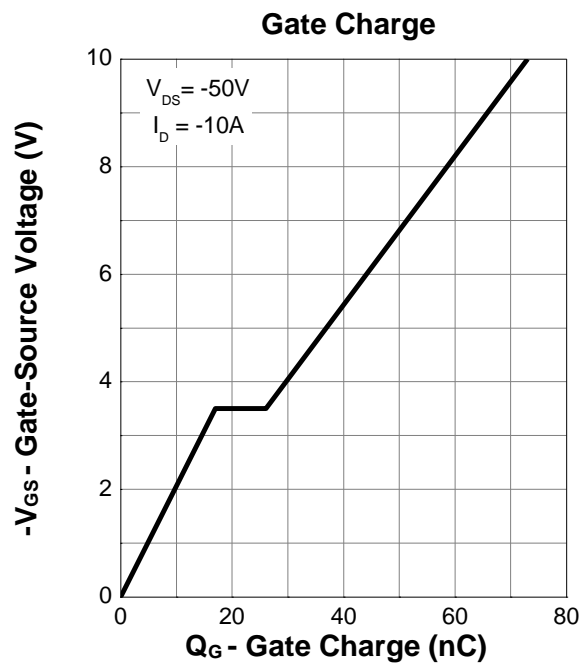
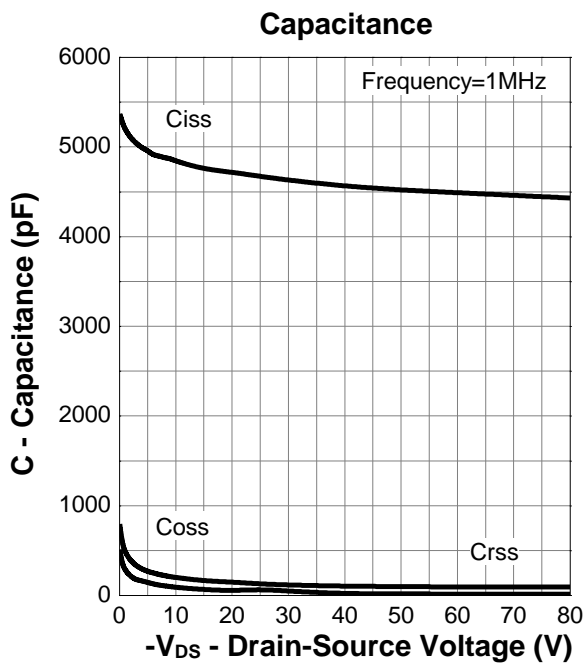
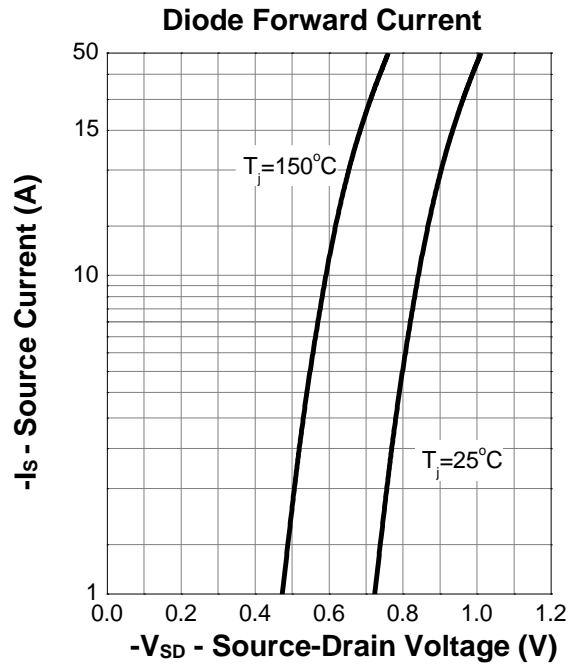
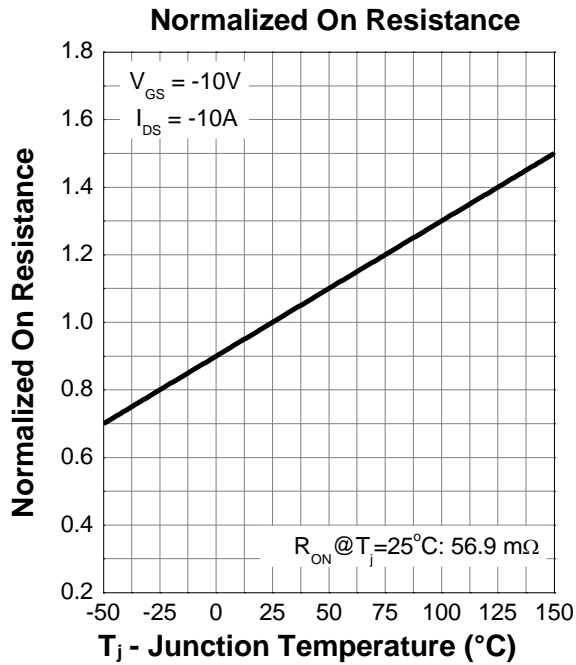


7. Typical Characteristics (cont.)





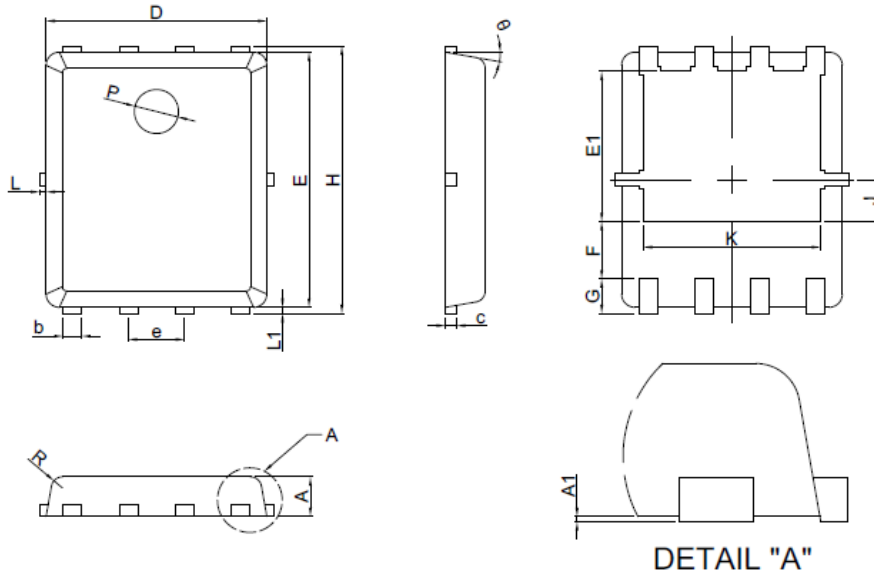
7. Typical Characteristics (cont.)





8.Package Dimensions

PDFN5x6 - 8L Package



Symbol	Dimensions In Millimeters	
	MIN.	MAX.
A	0.80	1.00
A1	0.00	0.05
b	0.35	0.49
c	0.254REF	
D	4.90	5.10
F	1.40REF	
E	5.70	5.90
e	1.27BSC	
H	5.95	6.20
L1	0.10	0.18
G	0.60REF	
K	4.00REF	
L	-	0.15
J	0.95BSC	
P	1.00REF	
E1	3.40REF	
θ	6°	14°
R	0.25REF	